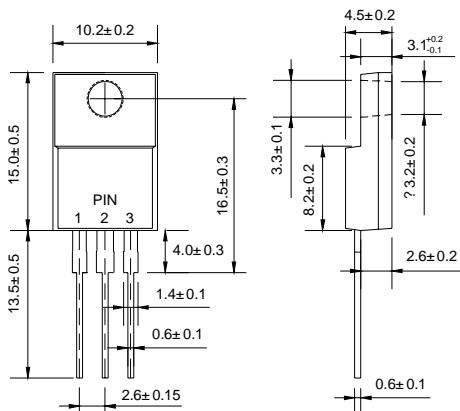


**SCHOTTKY BARRIER RECTIFIERS**
**VOLTAGE RANGE: 30 - 100 V  
CURRENT: 30 A**
**FEATURES**

- ◇ High surge capacity.
- ◇ For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications.
- ◇ Metal silicon junction, majority carrier conduction.
- ◇ High current capacity, low forward voltage drop.
- ◇ Guard ring for over voltage protection.

**MECHANICAL DATA**

- ◇ Case: JEDEC ITO-220AB, molded plastic body
- ◇ Terminals: Solderable per MIL-STD-750, Method 2026
- ◇ Polarity: As marked
- ◇ Position: Any
- ◇ Weight: 0.08ounce, 2.24 grams

**ITO-220AB**


Dimensions in millimeters

**MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS**

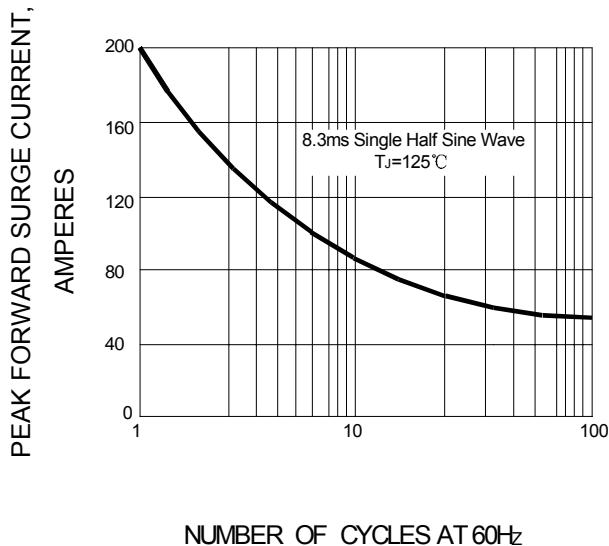
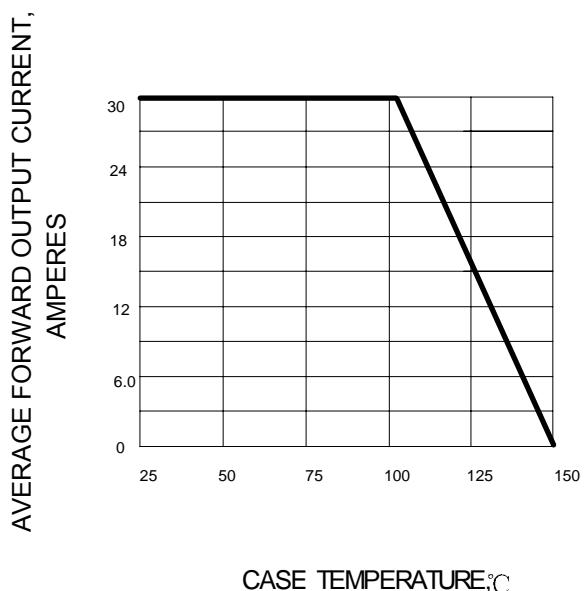
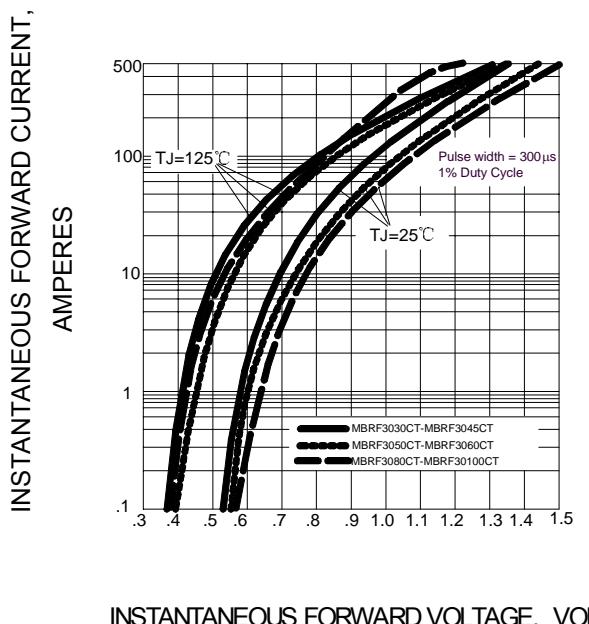
Ratings at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

		MBRF 3030CT	MBRF 3035CT	MBRF 3040CT	MBRF 3045CT	MBRF 3050CT	MBRF 3060CT	MBRF 3080CT	MBRF 30100CT	UNITS				
Maximum recurrent peak reverse voltage	$V_{RRM}$	30	35	40	45	50	60	80	100	V				
Maximum RMS Voltage	$V_{RMS}$	21	25	28	32	35	42	56	70	V				
Maximum DC blocking voltage	$V_{DC}$	30	35	40	45	50	60	80	100	V				
Maximum average forward total device rectified current @ $T_c = 105^\circ\text{C}$	$I_{F(AV)}$	30								A				
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load	$I_{FSM}$	200								A				
Maximum forward voltage (I <sub>F</sub> =15A, $T_c=25^\circ\text{C}$ ) (I <sub>F</sub> =15A, $T_c=125^\circ\text{C}$ ) (Note 1) (I <sub>F</sub> =30A, $T_c=25^\circ\text{C}$ ) (I <sub>F</sub> =30A, $T_c=125^\circ\text{C}$ )	$V_F$	-		0.80		0.85		0.65		V				
0.57 0.84 0.72		0.70		0.95		0.95		0.75						
Maximum reverse current @ $T_c=25^\circ\text{C}$ at rated DC blocking voltage @ $T_c=125^\circ\text{C}$	$I_R$	1.0				0.2				m A				
		60				40								
Maximum thermal resistance (Note 2)	$R_{\theta JC}$	6.8				4.4				°C/W				
Operating junction temperature range	$T_J$	- 55 ---- + 150								°C				
Storage temperature range	$T_{STG}$	- 55 ---- + 150								°C				

NOTE: 1. Pulse test: 300μs pulse width, 1% duty cycle.

2. Thermal resistance from junction to case.

**FIG.1 – PEAK FORWARD SURGE CURRENT****FIG.2 – FORWARD DERATING CURVE****FIG.3 – TYPICAL FORWARD CHARACTERISTIC****FIG.4 – TYPICAL REVERSE CHARACTERISTIC**